

AN ELECTRONIC SENSOR FOR ATMOSPHERIC RADICALS

FROM SILICON JUNCTIONLESS NANOWIRE TRANSISTORS

Sayantan Ghosh (@SGhosh_21), Muhammad Bilal Khan (@BilalKhan1), Ulrich Kentsch, Slawomir Prucnal, Rene Hübner, Artur Erbe and Yordan M. Georgiev (@yordanmg) Institute of Ion Beam Physics and Materials Research, Helmholtz-Zentrum Dresden Rossendorf (HZDR), Germany

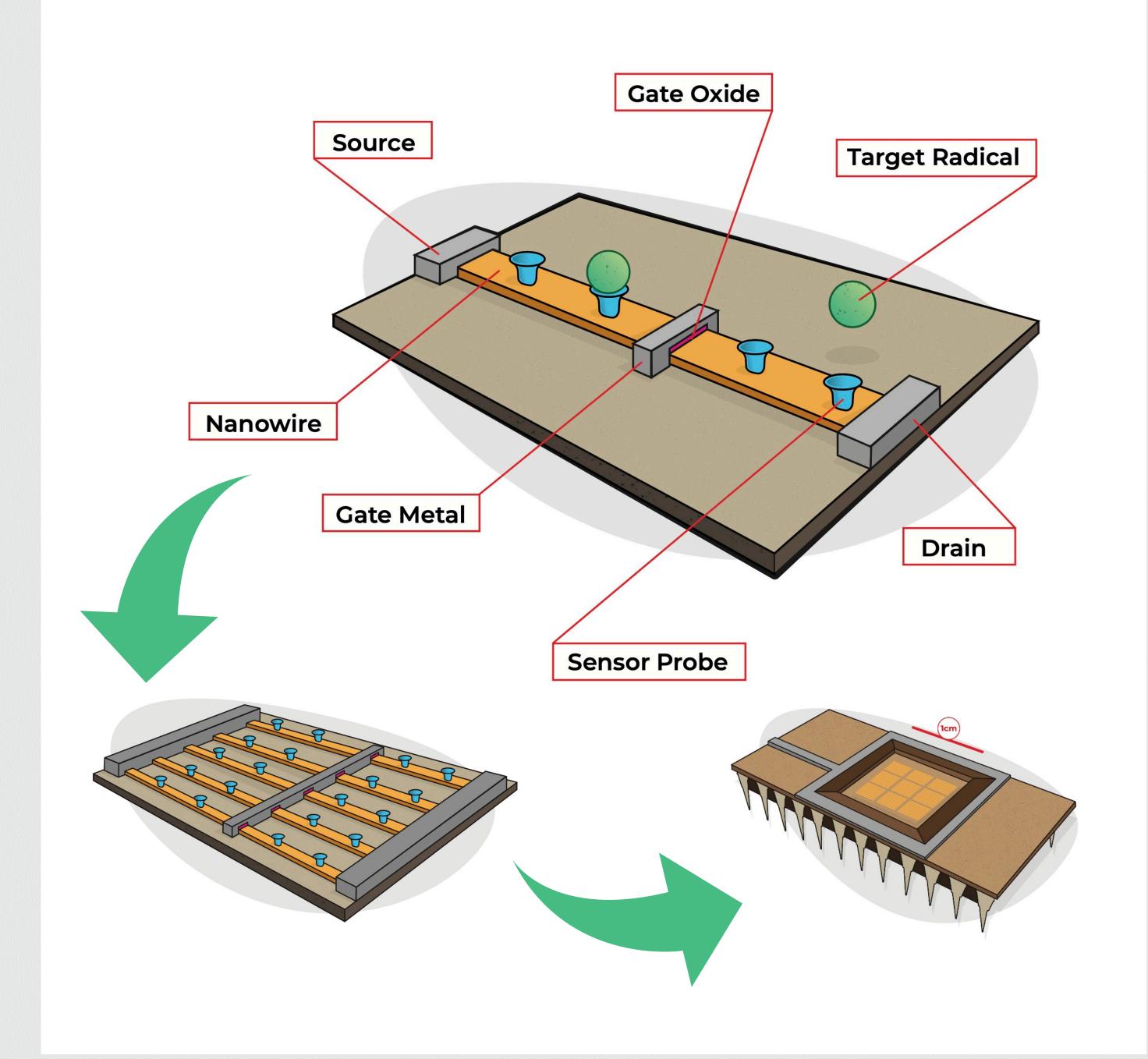
#RSCMat #RSCEnv #RSCNano

1. RADICAL: A novel electronic sensor for atmospheric radicals

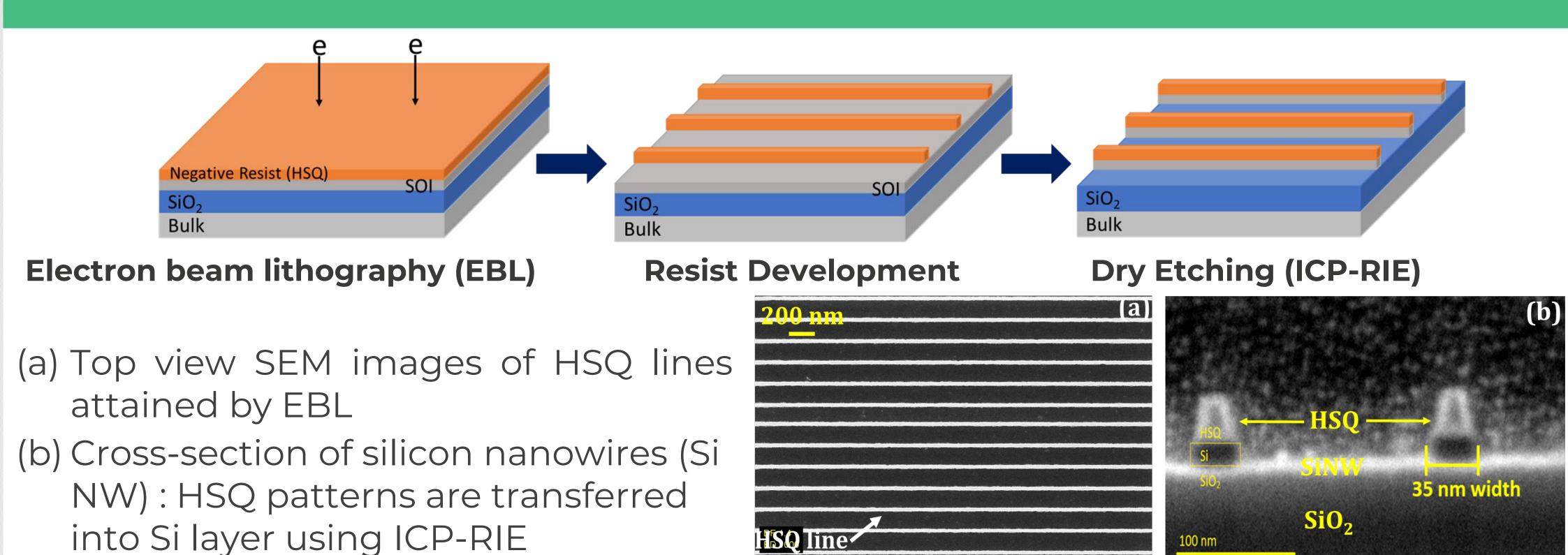
Atmospheric radicals like •OH and •NO₃ dominate the chemistry of the air we breathe, but remain difficult to detect in real-life environments.

Silicon junctionless nanowire transistors (JNTs) have shown promising sensing abilities in liquid phases but not yet in gas phase.

Here we present the first steps towards building an **electronic nose** for detecting atmospheric radicals, based on an array of JNTs.

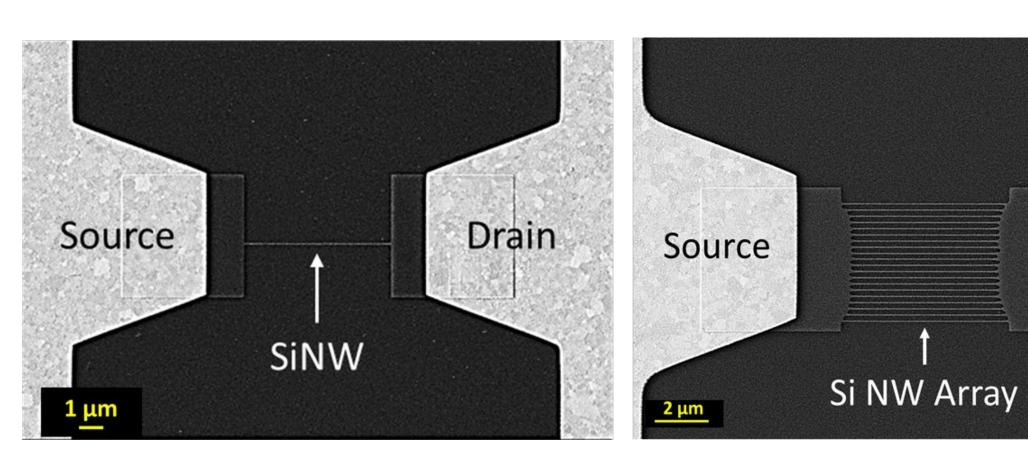


2. Top-down Si Nanowire Fabrication



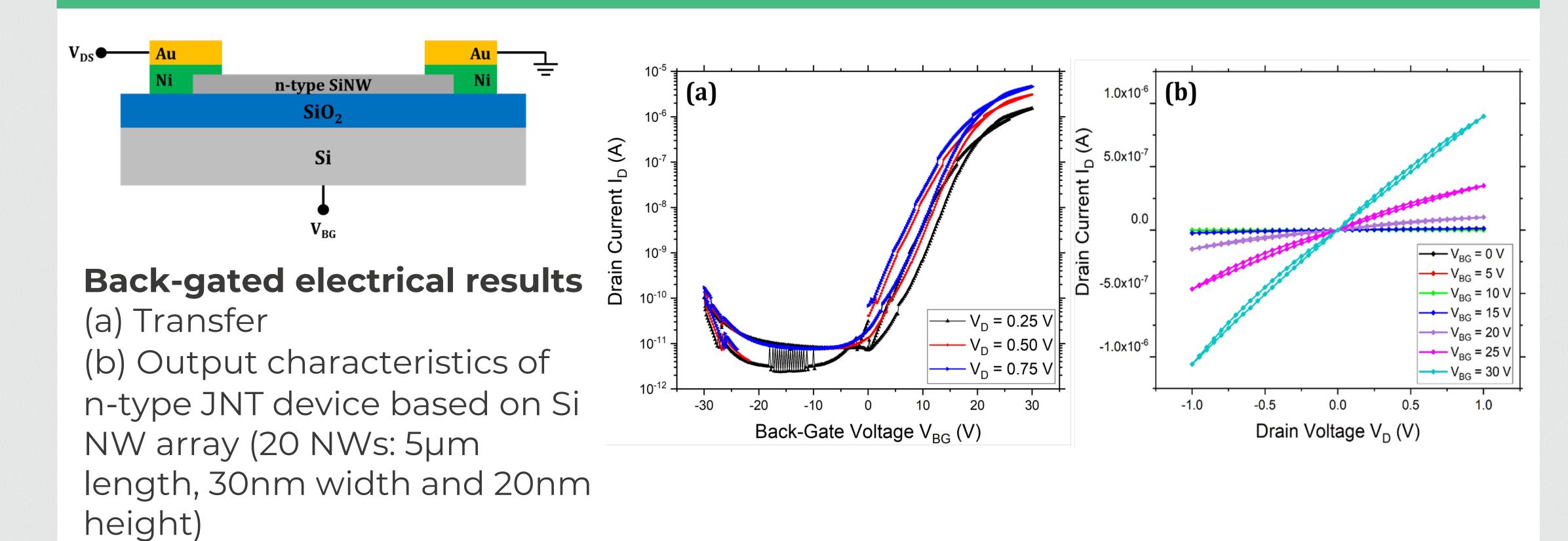
3. Source Drain Contact Formation

Contact patterning by PMMA resist coating and EBL. Metal deposition by e beam evaporation and lift-off. Metals used – 20 nm Nickel and 140 nm Gold.



Top view SEM image of JNT devices

4. Electrical Characteristics



RADICAL Project Acknowledgments

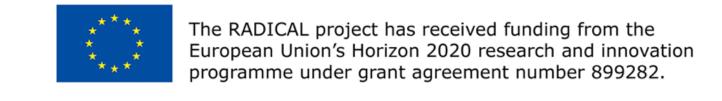












5. Outlook: Atmospheric Radical Sensing

Next steps

A comprehensive range of sensor performance tests within atmospheric simulation chambers and outdoor urban environments.



Future

A low-cost electronic sensor for atmospheric radicals and other gases

Find out more and follow our progress:

e: info@radical-air.eu

W: www.radical-air.eu



in radical-air